

L Number	Hits	Search Text	DB	Time stamp
1	117	((bitline (bit adj line)) with nitride with (spacer hardmask (hard adj mask) sidewall (side adj wall))) and (contact hole opening via plug landing land)	EPO; JPO; DERWENT; IBM_TDB	2004/07/24 15:51
2	326	((bitline (bit adj line)) with nitride with (spacer hardmask (hard adj mask) sidewall (side adj wall))) same ((contact hole opening via plug landing land) with (ild interlayer insulat\$6 dielectric organic (silicon adj (oxide dioxide))))	USPAT; US-PGPUB	2004/07/24 16:28
-	6	5387533.pn. 5824582.pn. 6010933.pn. 6077743.pn. 6184081.pn. 6436783.pn.	USPAT; US-PGPUB	2004/07/23 17:43
-	2061	438/639.ccls. 438/761.ccls. 438/763.ccls. 438/791.ccls. 438/792.ccls.	USPAT; US-PGPUB	2004/07/23 17:44
-	614	(bitline (bit adj line)) with nitride with (spacer hardmask (hard adj mask) sidewall (side adj wall))	USPAT; US-PGPUB	2004/07/23 17:52
-	149	(bitline (bit adj line)) with nitride with (spacer hardmask (hard adj mask) sidewall (side adj wall))	EPO; JPO; DERWENT; IBM_TDB	2004/07/23 17:48
-	452	((bitline (bit adj line)) with nitride with (spacer hardmask (hard adj mask) sidewall (side adj wall))) same (contact hole opening via plug landing land)	USPAT; US-PGPUB	2004/07/23 17:55
-	352	((bitline (bit adj line)) with nitride with (spacer hardmask (hard adj mask) sidewall (side adj wall))) same (contact hole opening via plug landing land)) same (ild interlayer insulat\$6 dielectric organic (silicon adj (oxide dioxide)))	USPAT; US-PGPUB	2004/07/23 17:55
-	16	(438/639.ccls. 438/761.ccls. 438/763.ccls. 438/791.ccls. 438/792.ccls.) and ((bitline (bit adj line)) with nitride with (spacer hardmask (hard adj mask) sidewall (side adj wall)))	USPAT; US-PGPUB	2004/07/23 17:56
-	93	((bitline (bit adj line)) with nitride with (spacer hardmask (hard adj mask) sidewall (side adj wall))) and ((high adj density adj plasma) hdpcvd (hdp adj cvd))	USPAT; US-PGPUB	2004/07/23 18:07